

300mW, PNP Small Signal Transistor

FEATURES

- AEC-Q101 qualified
- High current
- · Low power loss, high efficiency
- Ideal for automated placement
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free

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General switching and amplification

MECHANICAL DATA

• Case: SOT-23

- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Weight: 8.00mg (approximately)

KEY PARAMETERS							
PARAMETER	VALUE	UNIT					
V _{CBO}	-50	V					
VCEO	-45	V					
V _{EBO}	-5	V					
lc	-500	mA					
h _{FE}	400-600						
Configuration	Configuration Single die						



PACKAGE: SOT-23	PIN CONFIGURATION	CIRCUIT DIAGRAM
3 69 162	3	Collector (3) Base (1) Emitter (2)

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Power dissipation ⁽¹⁾	P _D	300	mW			
Collector-base voltage	V _{CBO}	-50	V			
Collector-emitter voltage	Vceo	-45	V			
Emitter-base voltage	V _{EBO}	-5	V			
Collector current	lc	-500	mA			
Junction temperature	TJ	-55 to +150	°C			
Storage temperature	T _{STG}	-55 to +150	°C			

Note:

1. Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint



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THERMAL PERFORMANCE						
PARAMETER	SYMBOL	TYP	UNIT			
Junction-to-ambient thermal resistance ⁽¹⁾	R _{ΘJA}	417	°C/W			

Thermal Performance Note:

1. Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint

PARAMETER	CONDITIONS		SYMBOL	MIN	TYP	MAX	UNIT
Collector-base	I _C = -10μA, I _E = 0A		V _(BR) CBO	-50	_	_	V
breakdown voltage	ις = τομπ, ιε -	- 0/1	V (BK)CBO				·
Collector-emitter	lo = -10mΔ lp	– 0Δ	V/22/222	-45	_	_	V
breakdown voltage	$I_{C} = -10 \text{mA}, I_{B} = 0 \text{A}$		V _(BR) CEO	-45	-		V
Emitter-base	$I_E = -1\mu A, I_C = 0A$		V/	-5	-	-	V
breakdown voltage			$V_{(BR)EBO}$				
Collector-base cut-off current	$V_{CB} = -45V, I_{E} = 0A$		Ісво	-	-	-0.1	μA
Emitter-base cut-off current	$V_{EB} = -4V, I_{C} = 0A$		I _{EBO}	-	-	-0.1	μA
	V _{CE} = -1V,	BC807-25H		160	-	400	
DC current gain	Ic = -100mA	BC807-40H	h _{FE}	250	-	600	-
	V _{CE} = -1V, I _C =	-500mA		40	-	-	
Collector-emitter saturation voltage	I _C = -500mA, I _B = -50mA		VCE(sat)	-	-	-0.7	V
Base-emitter saturation voltage	I _C = -500mA, I _B = -50mA		V _{BE(sat)}	-	-	-1.2	V
Base-emitter voltage	$V_{CE} = -1V$, $I_{C} = -500$ mA		V_{BE}	-	-	-1.2	V
Transition frequency	V _{CE} = -5V, I _C = -10mA, f = 100MHz		f⊤	100	-	-	MHz
Output capacitance	$V_{CB} = -10V$, $I_E = 0A$, $f = 1MHz$		C _{obo}	-	7	-	pF

ORDERING AND MARKING INFORMATION							
ORDERING CODE	PACKAGE	PACKING	DEVICE MARKING				
BC807-25H RFG	SOT-23	3,000 / 7" Tape & Reel	<u>5</u> B				
BC807-40H RFG	SOT-23	3,000 / 7" Tape & Reel	<u>5</u> C				



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Power Dissipation Curve

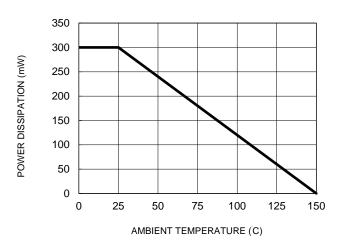


Fig.3 DC Current Gain vs. Collector Current

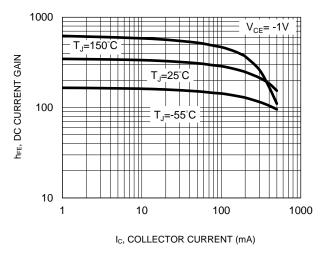


Fig.5 Base-Emitter Saturation Voltage vs. Collector Current

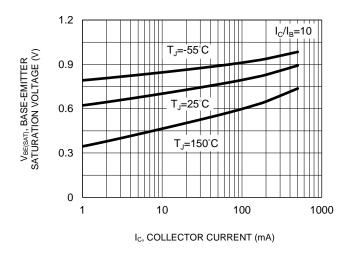
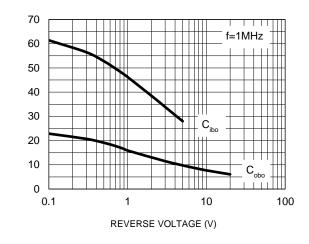


Fig.2 Typical Capacitance Characteristics



CAPACITANCE (pF)

Fig.4 Collector-Emitter Saturation Voltage vs.
Collector Current

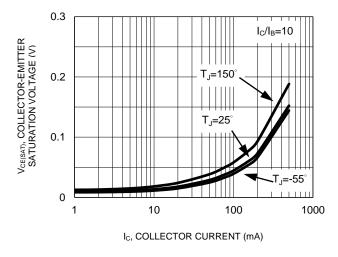
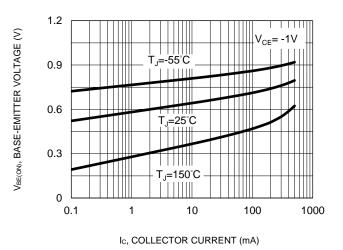
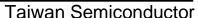


Fig.6 Base-Emitter Voltage vs. Collector Current

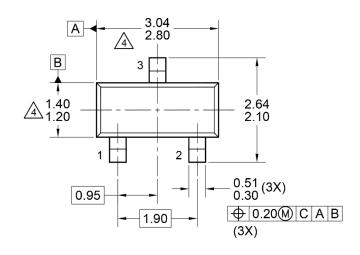


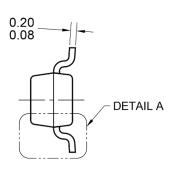


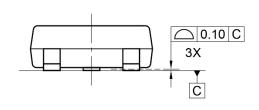


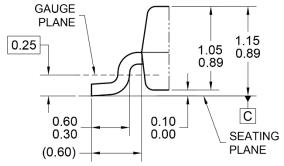
PACKAGE OUTLINE DIMENSIONS

SOT-23





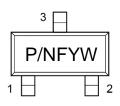




0.95

DETAIL A, ROTATED -90° (SCALE 2:1)

SUGGESTED PAD LAYOUT



NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. PACKAGE OUTLINE REFERENCE: JEDEC TO-236, ISSUE H, VARIATION AA.
- MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 5. DWG NO. REF: HQ2SD07-SOT23JEDEC-104 REV B.

MARKING DIAGRAM

P/N = Device marking
F = Factory code
Y = Year code

W = Bi-Week code (A~Z)



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